

54FCT574 Octal D-Type Flip-Flop with TRI-STATE® Outputs

General Description

The 'FCT574 is an octal flip-flop with a buffered common Clock (CP) and a buffered common Output Enable (\overline{OE}) . The information presented to the D inputs is stored in the flip-flops on the LOW-to-HIGH Clock (CP) transition.

The device is functionally identical to the 'FCT374 except for the pinouts.

Features

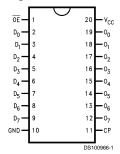
- Inputs and outputs on opposite sides of package allowing easy interface with microprocessors
- Useful as input or output port for microprocessors
- Functionally identical to 'FCT374
- TRI-STATE outputs for bus-oriented applications
- Output sink capability of 32 mA, source capability of 12 mA
- TTL input and output level compatible
- CMOS power consumption
- Standard Microcircuit Drawing (SMD) 5962-8951301

Ordering Code

Military	Package Number	Package Description
54FCT574DMQB	J20A	20-Lead Ceramic Dual-In-Line
54FCT574FMQB	W20A	20-Lead Cerpack
54FCT574LMQB	E20A	20-Lead Ceramic Leadless Chip Carrier, Type C

Connection Diagrams

Pin Assignment for DIP and Flatpak



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Pin Descriptions

Pin	Description		
Names			
D ₀ -D ₇	Data Inputs		
CP	Clock Pulse Input		
	(Active Rising Edge)		
ŌĒ	TRI-STATE Output Enable		
	Input (Active LOW)		
O ₀ -O ₇	TRI-STATE Outputs		

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Functional Description

The 'FCT574 consists of eight edge-triggered flip-flops with individual D-type inputs and TRI-STATE true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D inputs that meet the setup and hold times requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable (\overline{OE}) LOW, the contents of the eight flip-flops are available at the outputs. When \overline{OE} is HIGH, the outputs are in a high impedance state. Operation of the $\overline{\text{OE}}$ input does not affect the state of the flip-flops.

Inputs		Inputs Internal Ou		Outputs	Function
OE	CP	D	Q	0	
Н	H or L	Н	NC	Z	Hold
Н	Ν	L	L	Z	Load
Н	Ν	Н	Н	Z	Load
L	Ν	L	L	L	Data Available
L	N	Н	Н	Н	Data Available
L	H or L	L	NC	NC	No Change in Data
L	H or L	Н	NC	NC	No Change in Data

H = HIGH Voltage Level L = LOW Voltage Level

X = Immaterial

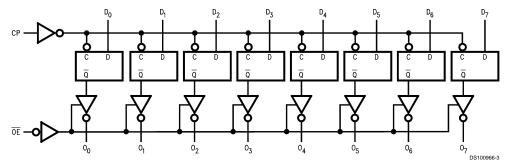
Z = High Impedance N = LOW-to-HIGH Transition

NC = No Change

Function Table

	Inputs		Internal Outputs		Function
ΟE	CP	D	Q	0	
Н	H or L	L	NC	Z	Hold

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Storage Temperature -65°C to $+150^{\circ}\text{C}$ Ambient Temperature under Bias -55°C to $+125^{\circ}\text{C}$

Junction Temperature under Bias

 $\begin{array}{lll} & & & -55^{\circ}\text{C to } +175^{\circ}\text{C} \\ V_{\text{CC}} \text{ Pin Potential to Ground Pin} & & -0.5V \text{ to } +7.0V \\ & & & & -0.5V \text{ to } +7.0V \\ & & & & & -0.5V \text{ to } +7.0V \\ \end{array}$

Voltage Applied to Any Output in

the Disabled or Power-Off State -0.5V to 5.5V in the HIGH State -0.5V to V_{CC}

Current Applied to Output in LOW State (Max) DC Latchup Source Current

twice the rated I_{OL} (mA) -500 mA

Recommended Operating Conditions

Free Air Ambient Temperature

Military –55°C to +125°C

Supply Voltage

Military +4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		FC	T574	Units	V _{cc}	Conditions
			Min	Max	1		
V _{IH}	Input HIGH Voltage		2.0		V		Recognized HIGH Signal
V _{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V _{CD}	Input Clamp Diode Voltage			-1.2	V	Min	I _{IN} = -18 mA
V _{OH}	Output HIGH	54FCT	4.3		V	Min	I _{OH} = -300 μA
	Voltage	54FCT	2.4		V	Min	I _{OH} = -12 mA
V _{OL}	Output LOW Voltage	54FCT		0.2	V	Min	I _{OL} = 300 μA
	Output LOW Voltage	54FCT		0.5	V	Min	I _{OL} = 32mA
I _{IH}	Input HIGH Current			5	μA	Max	V _{IN} = 2.7V (Note 3)
				5			$V_{IN} = V_{CC}$
I _{IL}	Input LOW Current			-5	μA	Max	V _{IN} = 0.5V (Note 3)
				-5			$V_{IN} = 0.0V$
I _{OZH}	Output Leakage Current			10	μA	0 - 5.5V	V _{OUT} = 2.7V; OE = 2.0V
I _{OZL}	Output Leakage Current			-10	μA	0 - 5.5V	V _{OUT} = 0.5V; OE = 2.0V
Ios	Output Short-Circuit Current		-60		mA	Max	V _{OUT} = 0.0V
I _{CCQ}	Power Supply Current			1.5	mA	Max	$V_{IN} = 0.2V$ or $V_{IN} = 5.3V$, $f_I = 0$ MHz
ΔI_{CC}	Power Supply Current			2.0	mA	Max	V _{IN} = 3.4V
I _{CCT}	Additional I _{CC} /Input			6.0	mA	Max	$V_I = V_{CC} - 2.1 \text{V or } V_{IN} = \text{GND, } f_{CP}$ = 10MHz, Outputs open, $\overline{\text{OE}} = \text{GND, one bit toggling at } f_I = 5\text{MHz,}$ 50% duty cycle
				5.5	mA	Max	$V_I = 5.3 \text{V or } V_{CC} = 0.2 \text{V}, f_{CP} = 10 \text{MHz}, \text{Outputs open, } \overline{\text{OE}} = \text{GND}, $ one bit toggling at $f_I = 5 \text{MHz}, 50 \%$ duty cycle
I _{CCD}	Dynamic I _{CC} No Load			0.40	mA/ MHz	Max	Outputs Open, \overline{OE} = GND, One bit toggling, 50% duty cycle, V_{IN} = 5.3V or V_{IN} = 0.2V

Note 3: Guaranteed, but not tested.

			54FCT		Fig. No.
Countries.	Paramatan.	$T_A = -55^{\circ}C \text{ to } +125^{\circ}C$ $V_{CC} = 4.5V \text{ to } 5.5V$ $C_L = 50 \text{ pF}$		Units	
Symbol	Parameter			***	
		Min	Max	1	
t _{PLH}	Propagation Delay	2.0	11.0	ns	Figure 4
t _{PHL}	CP to O _n	2.0	11.0		
t _{PZH}	Output Enable Time	1.5	14.0	ns	Figure 6
t _{PZL}		1.5	14.0		
t _{PHZ}	Output Disable Time	1.5	8.0	ns	Figure 6
t_{PLZ}		1.5	8.0		

AC Operating Requirements

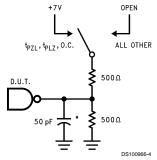
		54	FCT			
		$T_A = -55^{\circ}$	C to +125°C		Fig.	
Symbol	Parameter	V _{CC} = 4.9	$V_{CC} = 4.5V \text{ to } 5.5V$ $C_L = 50 \text{ pF}$		No.	
		C _L =				
		Min	Max			
t _s (H)	Setup Time, HIGH	3.5		ns	Figure 7	
t _s (L)	or LOW D _n to CP	3.5				
t _h (H)	Hold Time, HIGH	2.0		ns	Figure 7	
t _h (L)	or LOW D _n to CP	2.0				
t _w (H)	Pulse Width, CP,	7.0		ns	Figure 5	
t _w (L)	HIGH or LOW	7.0				

Capacitance

Symbol	Parameter	Тур	Units	Conditions T _A = 25°C
C _{IN}	Input Capacitance	5.0	pF	V _{CC} = 0V
C _{OUT} (Note 4)	Output Capacitance	9.0	pF	V _{CC} = 5.0V

Note 4: C_{OUT} is measured at frequency f = 1 MHz, per MIL-STD-883B, Method 3012.

AC Loading



*Includes jig and probe capacitance

FIGURE 1. Standard AC Test Load

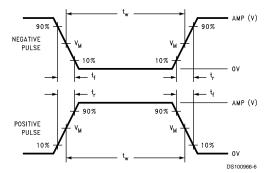


FIGURE 2. V_M = 1.5V

Input Pulse Requirements

Amplitude	nplitude Rep. Rate		t _r	t _f	
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns	

FIGURE 3. Test Input Signal Requirements

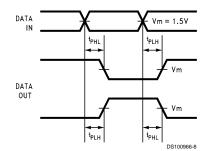


FIGURE 4. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

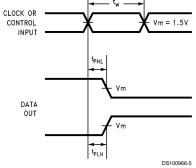


FIGURE 5. Propagation Delay, Pulse Width Waveforms

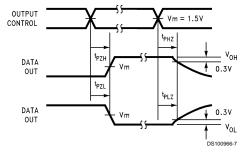


FIGURE 6. TRI-STATE Output HIGH and LOW Enable and Disable Times

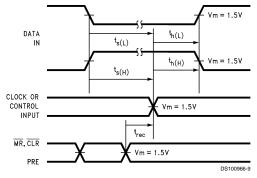
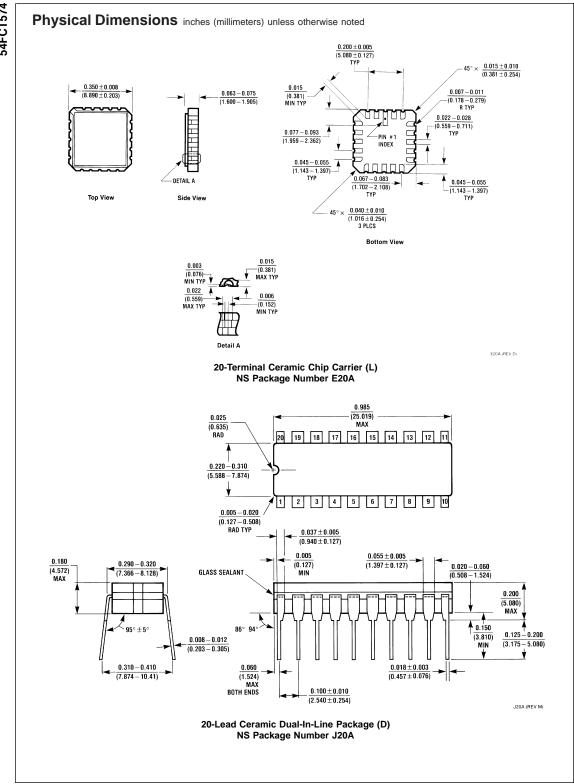
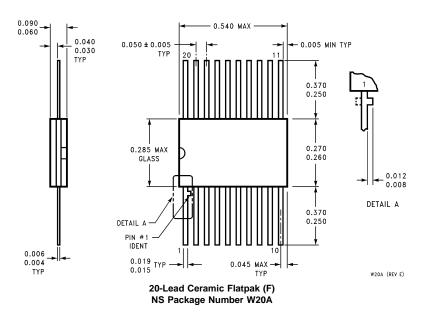


FIGURE 7. Setup Time, Hold Time and Recovery Time Waveforms



Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



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National Semiconductor Corporation Americas

Tel: 1-800-272-9959 Fax: 1-800-737-7018 Email: support@nsc.com

www.national.com

National Semiconductor

Europe
Fax: +49 (0) 1 80-530 85 86
Email: europe.support@nsc.com
Deutsch Tel: +49 (0) 1 80-530 85 85
English Tel: +49 (0) 1 80-532 78 32
Français Tel: +49 (0) 1 80-532 93 58
Italiano Tel: +49 (0) 1 80-534 16 80

National Semiconductor Asia Pacific Customer Response Group Tel: 65-2544466 Fax: 65-2504466 Email: sea.support@nsc.com National Semiconductor Japan Ltd. Tel: 81-3-5639-7560 Fax: 81-3-5639-7507

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